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			Application Number		
			Filing Date	08-17-2001	<u>e</u>
			First Named Inventor	JOHN L. FITZ	ā
			Group Art Unit		
			Examiner Name		- 0
Sheet		of 7_	Attorney Docket Number	FITZ 3-1-1-1	7

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W		CHIA-CHIEN LIN et al., "FACET-COATING EFFECTS ON THE 1.3UM 6399-6402 STRAINED MULTIPLE QUANTUM WELL ALGAZINA STAP LASER DRODES", JTAP, VOL37 1998 12	10
	2	H. TEMKIN etal., "INGAAS/INP QUANTUM WELLLASERS WITH SUB-MA THRESHOLD CUMENT," APL VOL57 NO.16 OCTOBER 15, 1990	1
	3	Y. YUAN etal., "EDGE-EMITTING LASERS WITH SHORT-PERIOD SEMICONDUCTORY BY 881- AIR DKIRIOUTED BRAGG REFLECTOR MIRRORS", IEEE PTL, YOLG NO.7, 7/97 663	
	4	E. HOFLING etal., "EDGE-EMITTING GAINAS-ALGAAS MICHOLASERS" IEEE PTL, VOL 11, NO. 8, PP. 943-945 AUGUST 1999	
8M	5	MOTH MADHAN et al., "CONTINUOUS WAVE OPERATION OF 1.55 MM IT AP VOL 38 A LIZHO-LIZYZ NOV. 1,199 GAINAS P/INP LASER WITH SEMICHDUCTUP/BEN FOCICUONITEME AKTUMIED BATHE ALTUMINED	
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